NSN 5961-01-290-5612

Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-290-5612 **Inclosure Material:** Ceramic and metal **Overall Length:** 1.600 inches **Overall Diameter:** 0.520 inches **Mounting Method:** Press fit Semiconductor Material: Silicon Voltage Rating In Volts Per Characteristic: 700.0 forward voltage, peak **Terminal Type And Quantity:** 2 insulated wire lead w/terminal lug and 2 case Shelf Life: N/a **Unit Of Measure:** Demilitarization:

No Fiig: A110a0